

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HC375AP, TC74HC375AF, TC74HC375AFN

## 4-BIT D TYPE LATCH

The TC74HC375A is a high speed CMOS D-TYPE LATCH fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

It contains two groups of 2-bit latches controlled by an enable input (G1·2 or G3·4) and each group can be used in different circuits.

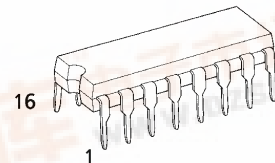
Data applied to the data inputs are transferred to the Q and  $\bar{Q}$  outputs when the enable inputs is high. When the enable input is low, the outputs are not affected.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

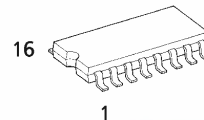
### FEATURES :

- High Speed..... $t_{pd} = 14ns(typ.)$  at  $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A(Max.)$  at  $T_a = 25^{\circ}C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (Min.)$
- Output Drive Capability..... 10 LSTTL Loads
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 4mA(Min.)$
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range... $V_{CC} (opr.) = 2V \sim 6V$
- Pin and Function Compatible with 74LS375

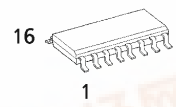
(Note) The JEDEC SOP (FN) is not available in Japan.



P (DIP16-P-300-2.54A)  
Weight : 1.00g (Typ.)

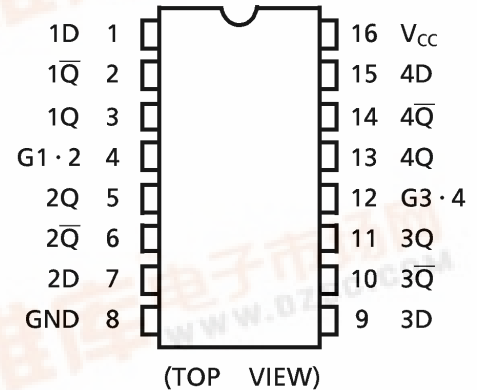


F (SOP16-P-300-1.27)  
Weight : 0.18g (Typ.)



FN (SOP16-P-150-1.27)  
Weight : 0.13g (Typ.)

### PIN ASSIGNMENT

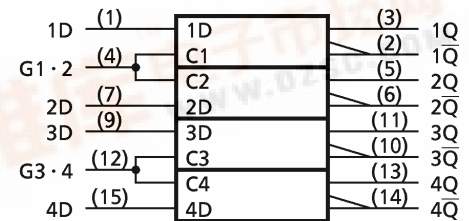


### TRUTH TABLE

INPUTS		OUTPUTS		FUNCTION
D	G	Q	$\bar{Q}$	
L	H	L	H	—
H	H	H	L	—
X	L	Q <sub>n</sub>	$\bar{Q}_n$	LATCH

X : Don't Care

### IEC LOGIC SYMBOL

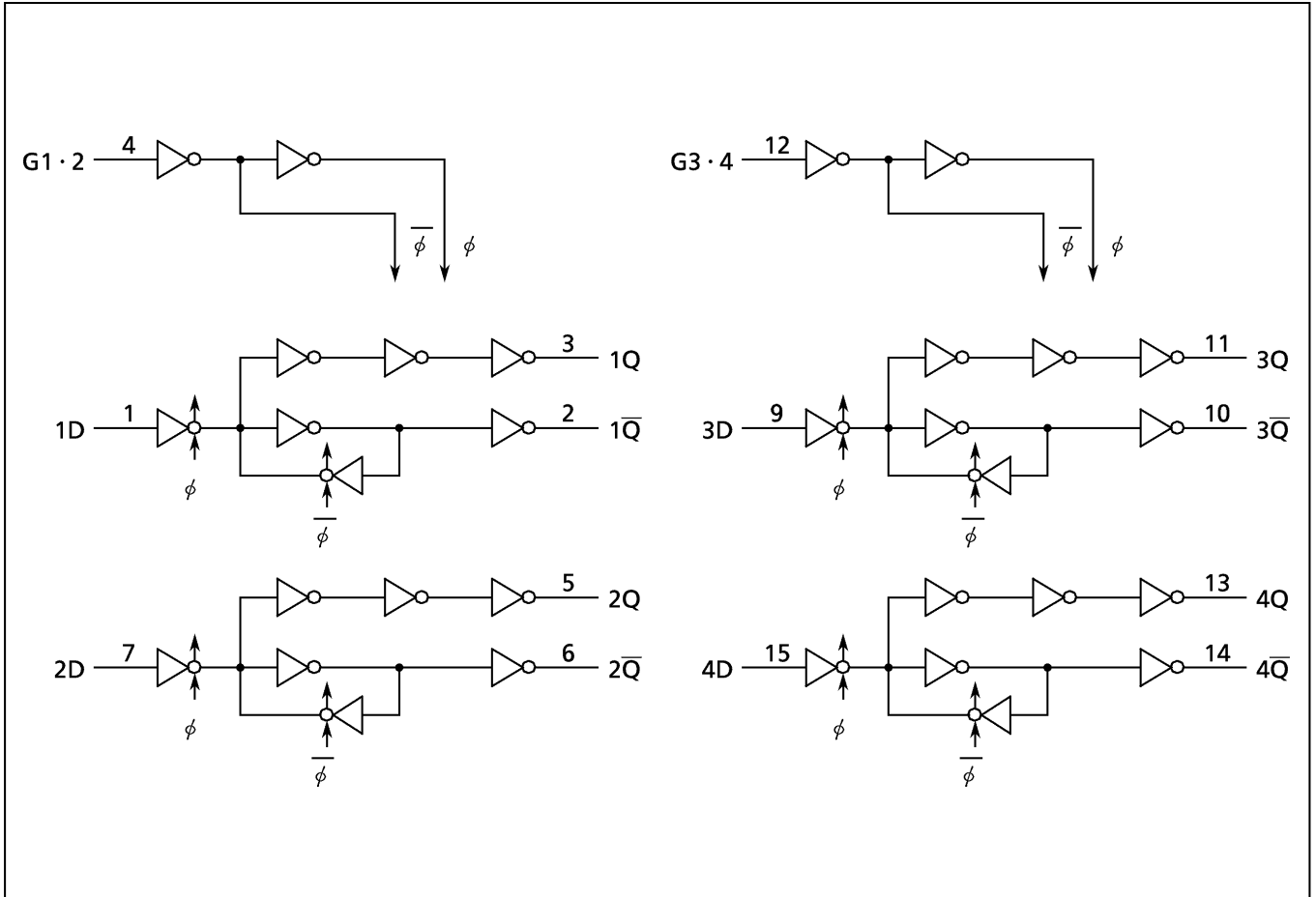


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**SYSTEM DIAGRAM**



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## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC}+0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC}+0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 50$	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2~6	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$t_r, t_f$	0~1000 ( $V_{CC} = 2.0\text{V}$ ) 0~500 ( $V_{CC} = 4.5\text{V}$ ) 0~400 ( $V_{CC} = 6.0\text{V}$ )	ns

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	$T_a = 25^{\circ}\text{C}$			$T_a = -40 \sim 85^{\circ}\text{C}$		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	$V_{IH}$		2.0	1.50	—	—	1.50	—	V	
			4.5	3.15	—	—	3.15	—		
			6.0	4.20	—	—	4.20	—		
Low - Level Input Voltage	$V_{IL}$		2.0	—	—	0.50	—	0.50	V	
			4.5	—	—	1.35	—	1.35		
			6.0	—	—	1.80	—	1.80		
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20\mu\text{A}$	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			6.0	5.9	6.0	—	5.9	—		
			$I_{OH} = -4\text{ mA}$ $I_{OH} = -5.2\text{ mA}$	4.5	4.18	4.31	—	4.13	—	
				6.0	5.68	5.80	—	5.63	—	
			Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 20\mu\text{A}$	2.0	—	0.0	
4.5	—	0.0					0.1	—	0.1	
6.0	—	0.0				0.1	—	0.1		
$I_{OL} = 4\text{ mA}$ $I_{OL} = 5.2\text{ mA}$	4.5	—				0.17	0.26	—	0.33	
	6.0	—				0.18	0.26	—	0.33	
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND				6.0	—	—	$\pm 0.1$	—
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	6.0	—	—	4.0	—	40.0		

TIMING REQUIREMENTS ( Input  $t_r = t_f = 6ns$  )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}(V)$	Ta = 25°C		Ta = -40~85°C	UNIT
				TYP.	LIMIT	LIMIT	
Minimum Pulse Width ( G )	$t_{W(H)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Set-up Time	$t_s$		2.0	—	75	95	
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Hold Time	$t_h$		2.0	—	0	0	
			4.5	—	0	0	
			6.0	—	0	0	

AC ELECTRICAL CHARACTERISTICS (  $C_L = 15pF$ ,  $V_{CC} = 5V$ , Ta = 25°C, Input  $t_r = t_f = 6ns$  )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	$t_{TLH}$		—	4	8	ns
	$t_{THL}$					
Propagation Delay Time ( D-Q, $\bar{Q}$ )	$t_{pLH}$		—	14	20	
	$t_{pHL}$					
Propagation Delay Time ( G-Q, $\bar{Q}$ )	$t_{pLH}$		—	13	20	
	$t_{pHL}$					

AC ELECTRICAL CHARACTERISTICS (  $C_L = 50pF$ , Input  $t_r = t_f = 6ns$  )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}(V)$	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	$t_{TLH}$		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time ( D-Q, $\bar{Q}$ )	$t_{pLH}$		2.0	—	60	120	—	150	
			4.5	—	17	24	—	30	
			6.0	—	15	20	—	26	
Propagation Delay Time ( G-Q, $\bar{Q}$ )	$t_{pLH}$		2.0	—	56	120	—	150	
			4.5	—	16	24	—	30	
			6.0	—	14	20	—	26	
Input Capacitance	$C_{IN}$			—	5	10	—	10	pF
Power Dissipation Capacitance	$C_{PD}(1)$			—	55	—	—	—	

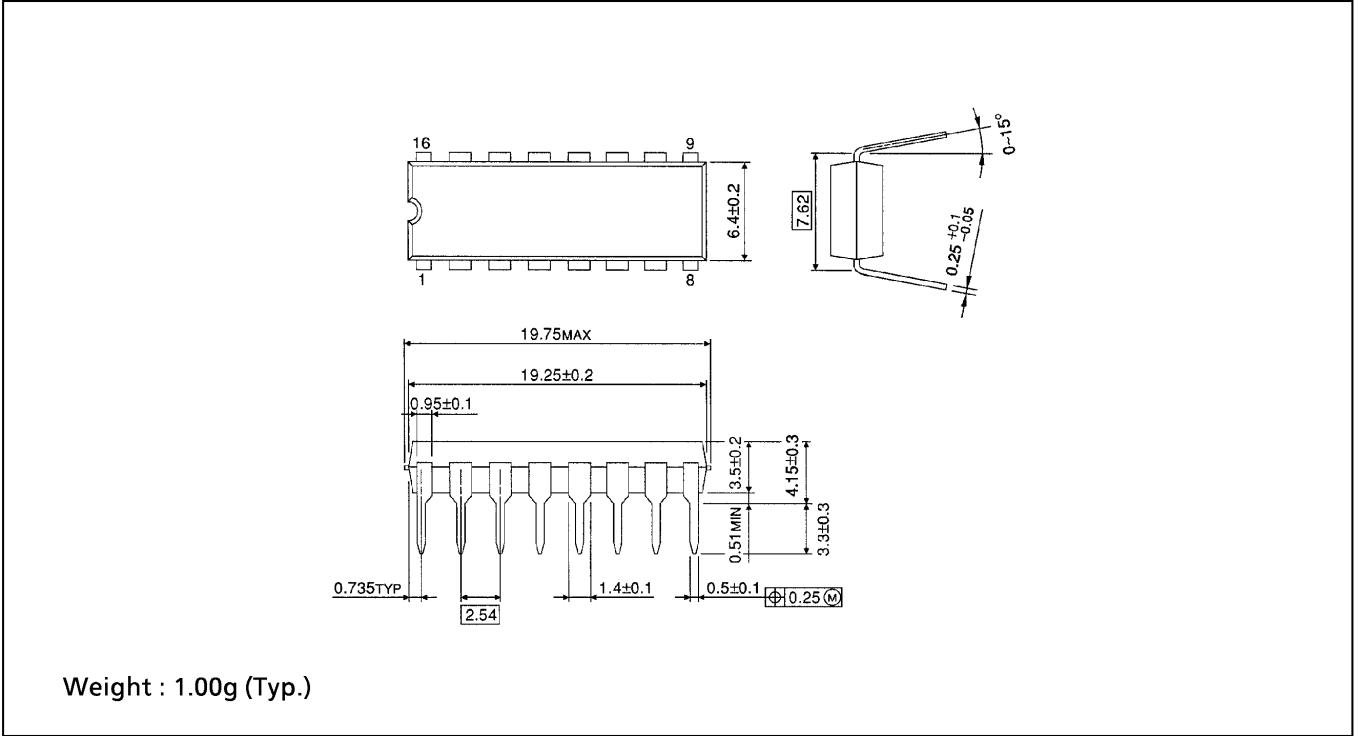
Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per Latch)}$$

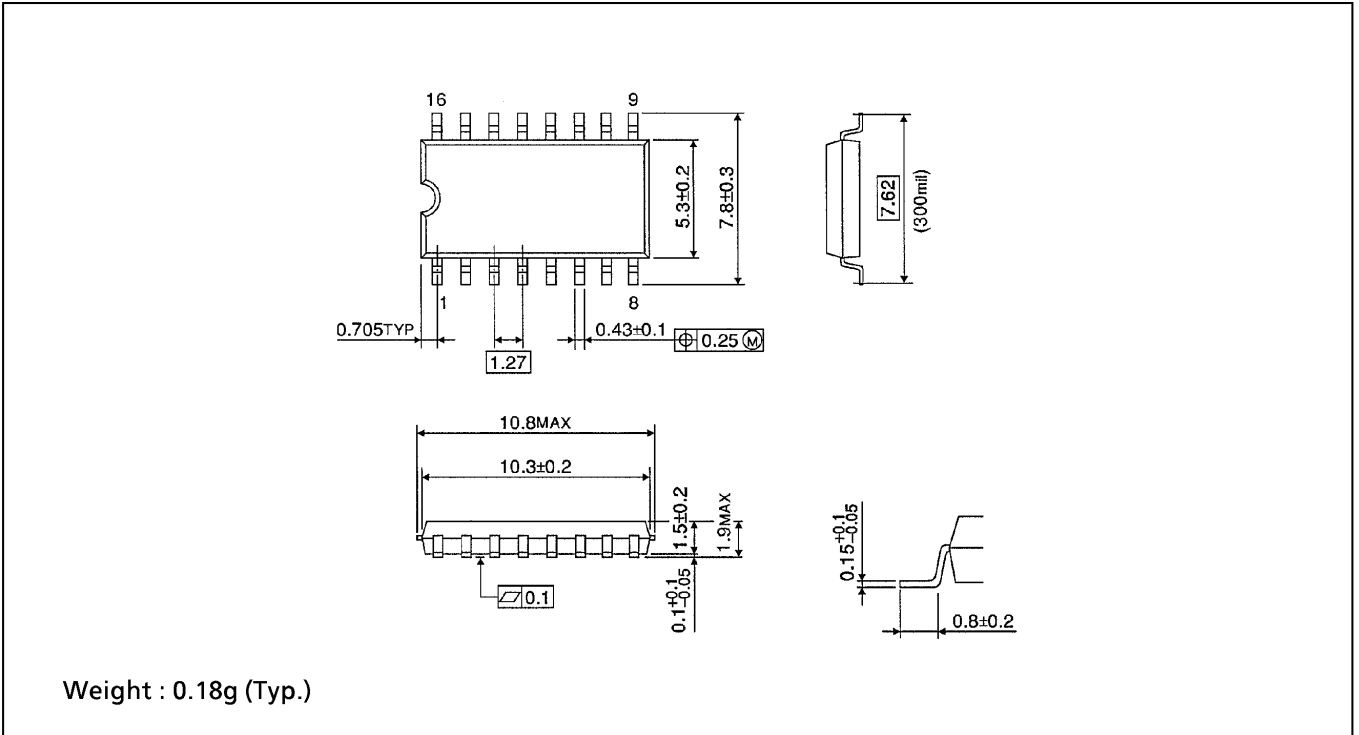
**DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)**

Unit in mm



**SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)**

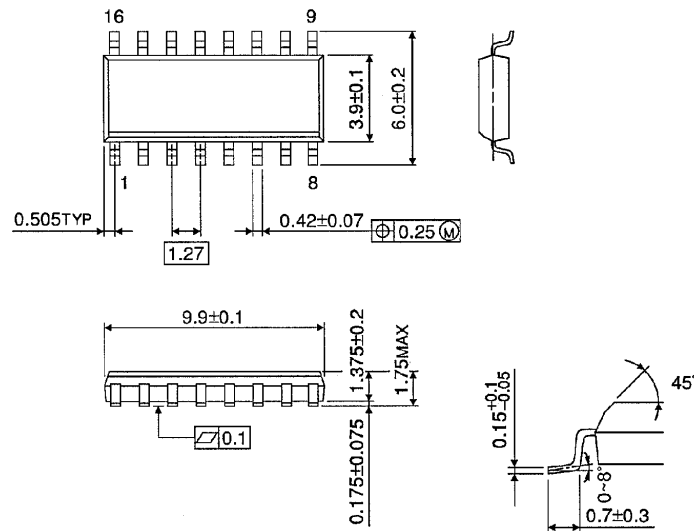
Unit in mm



**SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150 -1.27)**

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)